

# Valley polarisation assisted spin polarisation in Si MOSFETs

Vincent Renard

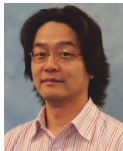
[vincent.renard@cea.fr](mailto:vincent.renard@cea.fr)

Université Grenoble Alpes / CEA INAC

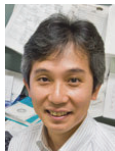
UNIVERSITÉ  
GRENOBLE  
ALPES



# Thanks



K. Takashina



A. Fujiwara



Y. Hirayama



B. Piot



G. Fleury



X. Waintal



# Agenda

Single particle picture

Previous results

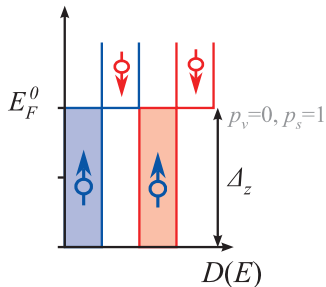
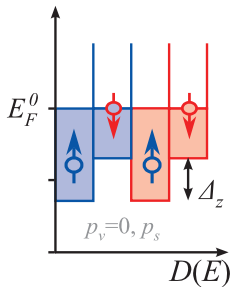
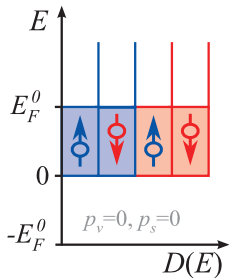
Our samples / results





Comparison with Quantum Monte carlo / Discussion

Advertising

# Single particle picture

Valley unpolarised 2DEG



 Spin up       Valley +  
 Spin down       Valley -

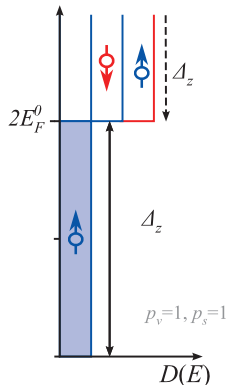
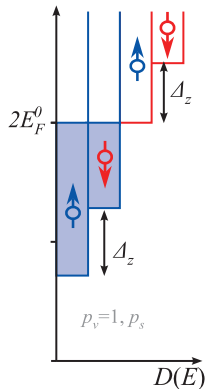
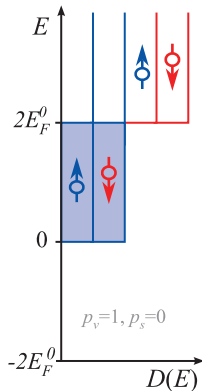
$$\Delta_z = g\mu_B B$$

$$p_s = \frac{n_{\uparrow} - n_{\downarrow}}{n_{\uparrow} + n_{\downarrow}}$$

$$B_p = \frac{2E_F^0}{g\mu_B}$$

# Single particle picture

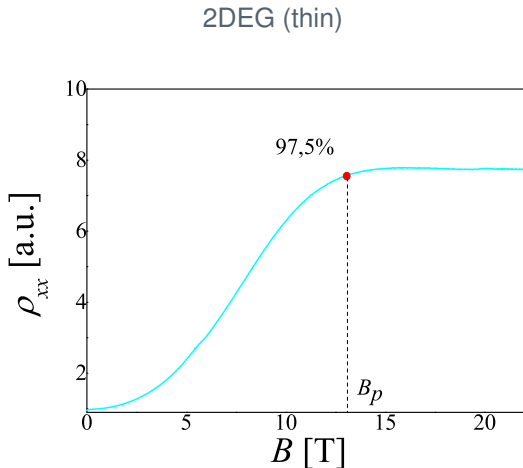
Valley polarised 2DEG



$$B_p = \frac{4E_F^0}{g\mu_B}$$

# Determination of $B_p$

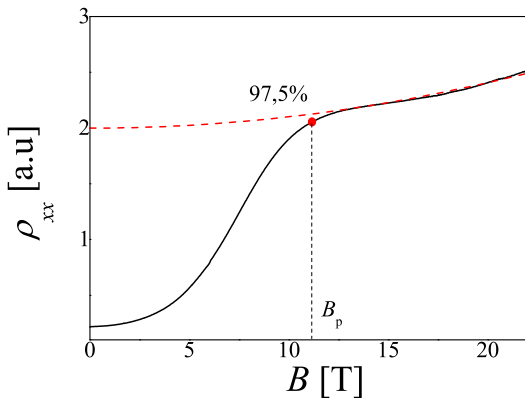
Magnetoresistance in parallel magnetic fields



# Determination of $B_p$

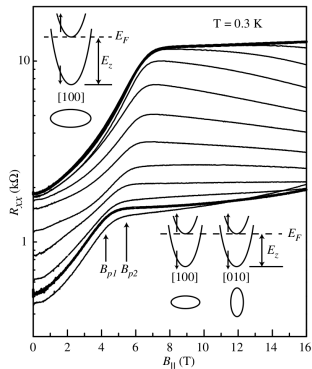
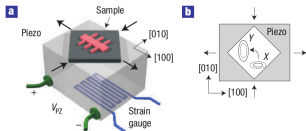
Magnetoresistance in parallel magnetic fields

Real 2DEG



# Previous results

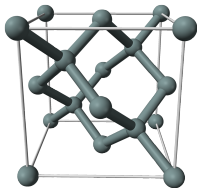
## AIAs



Shayegan *et al.* Phys. Rev. Lett. **92** 246804 (2004); PRB **78**, 161301(R) (2008);  
PRB, **81** 235305 (2010)

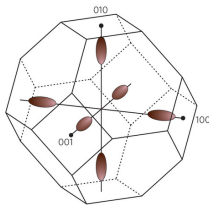


Si Crystal



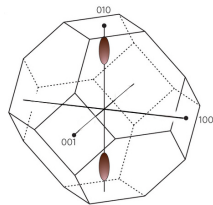
Diamond structure

Bulk



6 valleys

Confined in z direction

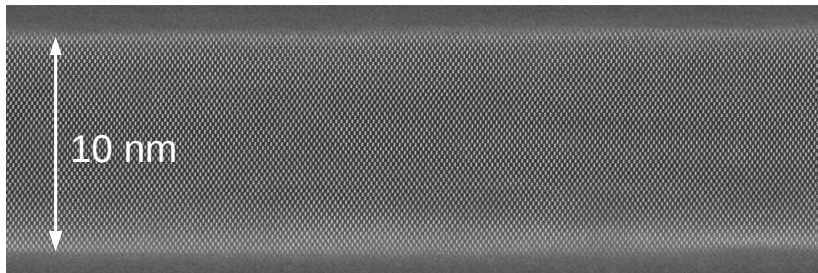


2 valleys

$$m_l = 0.9m_0$$

$$m_t = 0.2m_0$$

thermal oxide



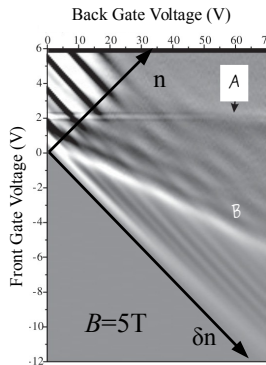
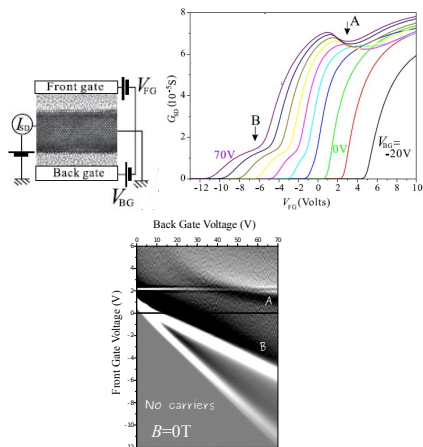
SIMOX oxide

Samples from NTT BRL (Atsugi, Japan)

Image by D. Cooper @ Leti

# Our samples

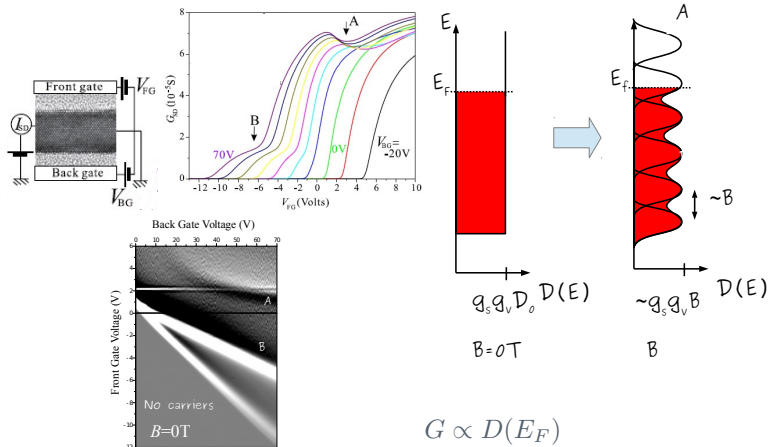
## Valley polarisation



$$n = n_F + n_B ; \delta n = n_B - n_F$$

# Our samples

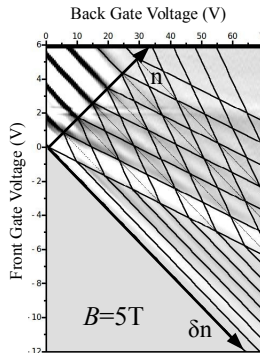
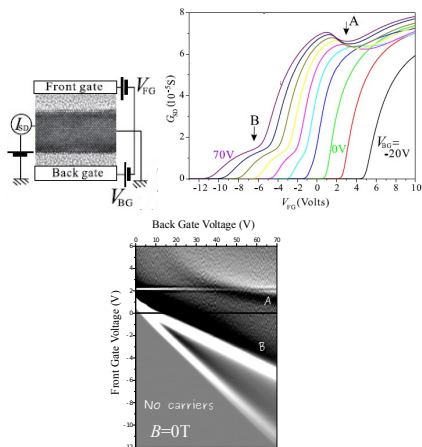
## Valley polarisation



K. Takashina *et al.* PRL (2006)

# Our samples

## Valley polarisation

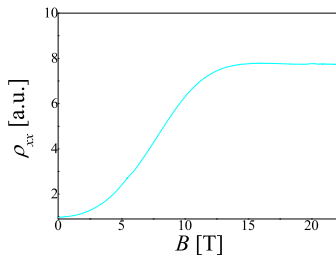


$$n = n_F + n_B ; \delta n = n_B - n_F$$

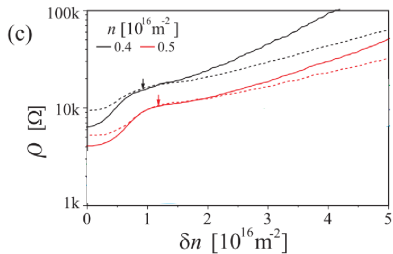
$$\Delta_v = \alpha \delta n$$

$$\alpha = 0.46 \text{ meV}/(10^{15} \text{ m}^{-2})$$

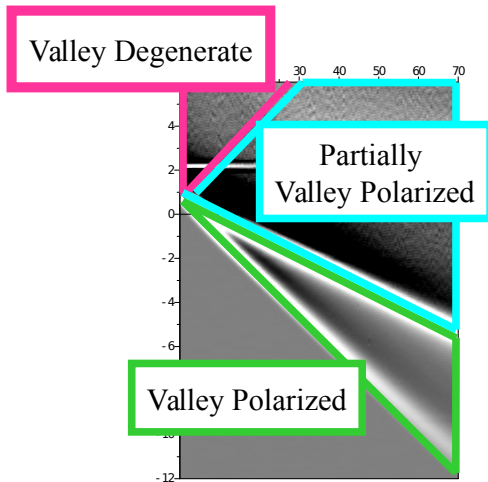
K. Takashina *et al.* PRL (2006)



Magnetoresistance

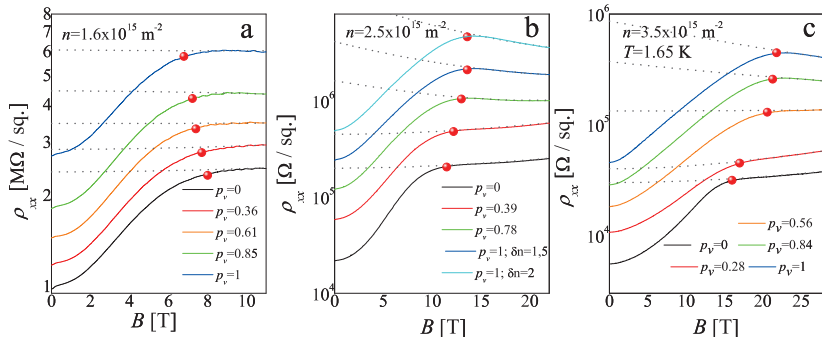


Valleyresistance



# Dependence of $B_p$ on valley polarization

Experiment

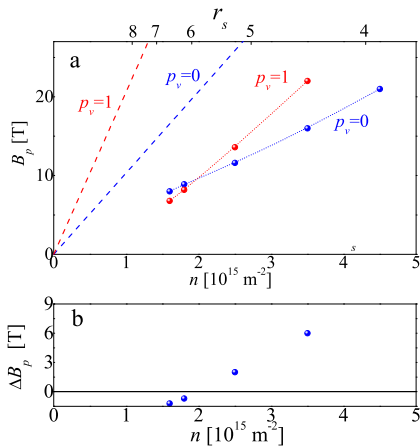


Consistent with measurements in AIAs

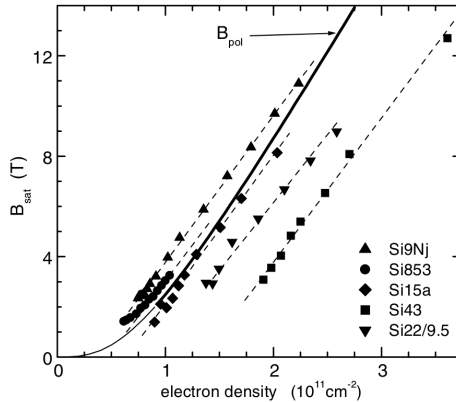
Shayegan *et al.* PRL (2004), PRB (2008), PRB (2010)



# Comparison with non-interacting theory

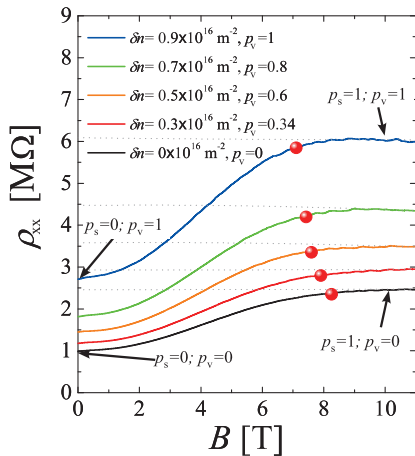


$$r_s = \frac{1}{(\pi n^{-1/2}) a_B}$$

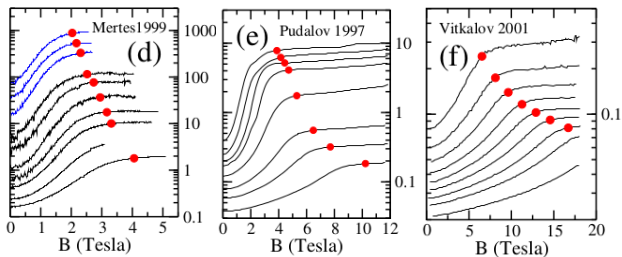


# Exclusion of disorder

magneto- and valley-resistance



Si at  $p_v = 0$



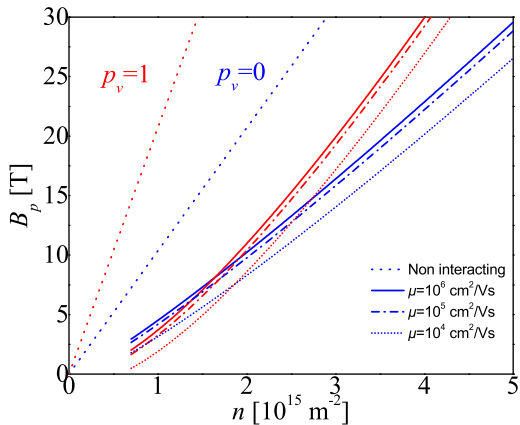
ingredients: interactions and white noise disorder

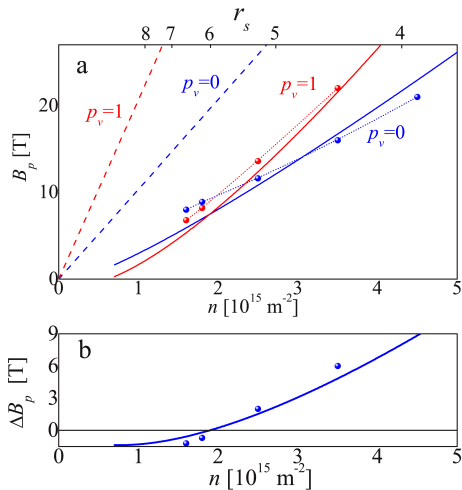
input : sample mobility at high density

Fleury & Waintal PRB (2010)

# Quantum Monte Carlo

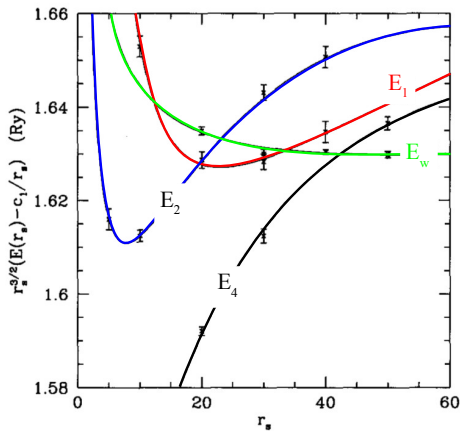
With Valley polarization





# Discussion

QMC with valleys in clean 2DEG

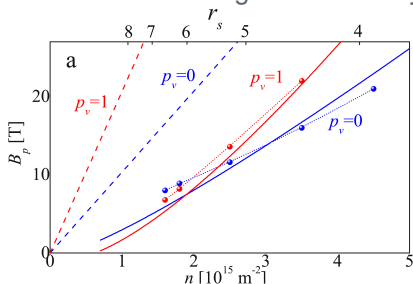


QMC in clean 2DEG by Conti and Senatore EPL (1996)

# Discussion

What does our result tell us?

- ▶  $p_v = 0$  is more stable vs ferromagnetic instability than  $p_v = 1$



- ▶ The prediction remains valid in disordered systems